# NSN 5962-01-116-8676

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## **Body Length:**

Between 1.065 inches and 1.105 inches

# Body Width:

Between 0.380 inches and 0.393 inches

# **Body Height:**

0.125 inches

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **End Application:**

Radio set, type an/arc-190

### Features Provided:

Hermetically sealed and monolithic and negative outputs and positive outputs and w/buffered output and w/enable and 3-state output

#### **Inclosure Material:**

# Ceramic and glass

#### Inclosure Configuration:

Dual-in-line

### **Output Logic Form:**

P-type metal oxide-semiconductor logic

### Input Circuit Pattern:

10 input

## **Terminal Surface Treatment:**

Solder

### Voltage Rating And Type Per Characteristic:

0.3 volts power source

### **Time Rating Per Chacteristic:**

1000.00 nanoseconds propagation delay time, low to high level output and 1000.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Rom

#### **Memory Capacity:**

Unknown

#### **Test Data Document:**

13499-351-8530 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## Terminal Type And Quantity:

22 printed circuit

# Shelf Life:

N/a

#### Unit Of Measure:

# Demilitarization:

Yes - demil/mli

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